

DCL32xx00

DCL320C00 / DCL320D00 / DCL321C00 / DCL321D00

1. Applications

- Industrial automation systems
- Motor control
- Inverter
- Switching power supply

2. Description

DCL320C00/DCL320D00/DCL321C00/DCL321D00 are low power dual-channel digital isolators. Outstanding performance characteristics are achieved by Toshiba CMOS technology and the magnetic coupling structure. In addition, they comply with UL 1577 and has a 3000Vrms rating as a withstand isolation voltage. These products can operate with a temperature range of -40 to 125 °C and a wide supply voltage of 2.25 to 5.5 V.

3. Features

Data rate	: Up to 25 Mbps
Supply voltage	: 2.25 V to 5.5 V
Temperature Range	: -40 °C to 125 °C
Propagation Delay	: 33 ns Typ. (5.0 V operation)
Default Output	: High and Low Options
High CMTI(min.)	: ±30 kV/μs
Withstand Isolation Voltage	: 3 kVrms
Package	: 8pin SOIC Narrow body
Safety-Related Certification	: UL1577, CQC, VDE DIN EN 60747-17
UL	: UL1577, File No. E519997
cUL	: CSA Component Acceptance Service Notice No. 5A
VDE	: DIN EN IEC 60747-17 (VDE 0884-17) (Planning)
CQC	: GB 4943.1-2022 (Planning)

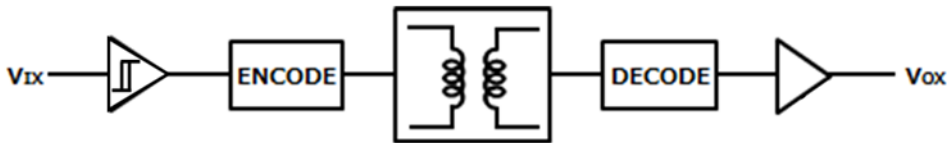
Start of commercial production

2026-07

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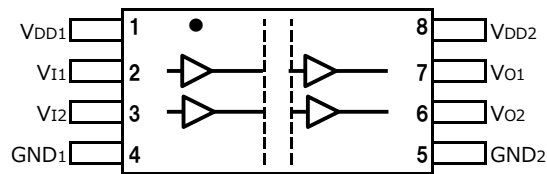
4. Internal Circuit



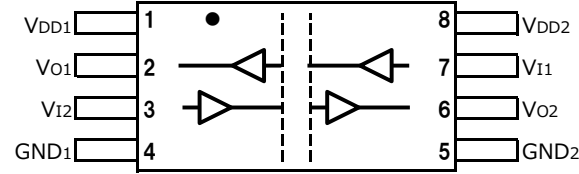
5. Pin configuration and Functions

Pin Layout

DCL320C00 / DCL320D00



DCL321C00 / DCL321D00



Pin Function

PIN			I/O	DESCRIPTION
NAME	DCL320C00 DCL320D00	DCL321C00 DCL321D00		
V_{DD1}	1	1	—	Power Supply, side 1
V_{I1}	2	7	I	Input, Channel1
V_{I2}	3	3	I	Input, Channel2
$GND1$	4	4	—	GND connection for V_{DD1} , side 1
$GND2$	5	5	—	GND connection for V_{DD2} , side 2
V_{O2}	6	6	O	Output, Channel2
V_{O1}	7	2	O	Output, Channel1
V_{DD2}	8	8	—	Power Supply, side 2

6. Functional Description

DCL320C00/DCL320D00 / DCL321C00/DCL321D00

V _{DDI}	V _{DDO}	INPUT (V _{IX})	OUTPUT (V _{OX})	COMMENTS
PU	PU	L	L	Normal Operation
		H	H	
PU	PD	L or H	Undetermined	When V _{DDO} is unpowered, a channel output is undetermined.
PD	PU	X	Default	Default mode: DCL320C00 = L, DCL320D00 = H DCL321C00 = L, DCL321D00 = H
PD	X	H	-	Don't use since a certain voltage will be output through the internal ESD circuit.

PU= Powered up (V_{DD} ≥ 2.25 V), PD= Powered down (V_{DD} < 2.25 V → 0 V), H = High level, L = Low level, X = Don't Care

V_{DDI}, V_{DDO} : Supply voltages on the input and output sides of each channel.

V_{IX}, V_{OX} : Input and output signals of each channel.

When the input pin (V_{IX}) on the power-off side is set to "H", power is supplied to the device via the ESD circuit, so use is prohibited.
Don't leave the Input pin (V_{IX}) on the power ON side open because terminal circuits don't have pull-down resistor or pull-down resistor inside.

7. Absolute Maximum Ratings ($T_a = 25^\circ\text{C}$)

PARAMETER	SYMBOL	MIN	MAX	UNIT
Power supply voltage	V_{DD1}, V_{DD2}	-0.5	6.0	V
Input Voltage	V_I	-0.5	$V_{DDX}+0.5^{(\text{Note1})}$	V
Output Voltage	V_O	-0.5	$V_{DDX}+0.5^{(\text{Note1})}$	V
Output Current	I_O	-15	15	mA
Storage Temperature	T_{stg}	-65	150	$^\circ\text{C}$
Operating Temperature	T_{opr}	-40	125	$^\circ\text{C}$
Soldering Temperature (10 s)	T_{sol}	-	260	$^\circ\text{C}$
Maximum Withstanding Isolation Voltage (60 s)	BV_s	-	3000	Vrms

Note1: Maximum voltage must not exceed 6 V. X = 1 or 2.

8. Recommended Operating Conditions (Note)

PARAMETER	SYMBOL	MIN	MAX	UNIT
Power supply voltage	V_{DD1}, V_{DD2}	2.25	5.5	V
Junction Temperature	T_J	-40	150	$^\circ\text{C}$
Operating Temperature	T_{opr}	-40	125	$^\circ\text{C}$

Note: The recommended operating conditions are given as a design guide necessary to obtain the intended performance of the device. Each parameter is an independent value. When creating a system design using this device, the electrical characteristics specified in this data sheet should also be considered.

Note: A ceramic capacitor (0.1 μF) should be connected between pin 1 (V_{DD1}) and pin 4 (GND_1) for V_{DD1} and between pin 8 (V_{DD2}) and pin 5 (GND_2) for V_{DD2} and should be the layout on the IC as close as possible (less than 10 mm). Otherwise, the IC may not switch properly.

9. Electrical Characteristics

9.1. Electrical Characteristics – 5 V Supply

All typical specifications are at $T_a = 25^\circ\text{C}$, $V_{DD1} = V_{DD2} = 5\text{ V}$. Minimum/maximum specifications apply over the entire recommended operating range of $4.5\text{ V} \leq V_{DD1} \leq 5.5\text{ V}$, $4.5\text{ V} \leq V_{DD2} \leq 5.5\text{ V}$, and $-40^\circ\text{C} \leq T_a \leq 125^\circ\text{C}$, unless otherwise noted.

PARAMETER	TEST CONDITIONS	Fig.	SYMBOL	MIN	TYP.	MAX	UNIT
DC SPECIFICATIONS							
Output Voltage Logic High	V _{IX} = H , I _{OH} = -20 μA	Fig. 12.1	V _{OH}	V _{DDO} ^(Note1) -0.1	V _{DDO} ^(Note1)	-	V
	V _{IX} = H , I _{OH} = -4 mA			V _{DDO} ^(Note1) -0.4	V _{DDO} ^(Note1) -0.2	-	
Output Voltage Logic Low	V _{IX} = L , I _{OL} = 20 μA	Fig. 12.1	V _{OL}	-	0.0	0.1	V
	V _{IX} = L , I _{OL} = 4 mA			-	0.2	0.4	
Output impedance	-	Fig. 12.1	Z _O	-	50	-	Ω
High-level input voltage	-	Fig. 12.2	V _{IH}	0.7*V _{DDI} ^(Note1)	-	-	V
Low-level input voltage	-	Fig. 12.2	V _{IL}	-	-	0.3*V _{DDI} ^(Note1)	V
Input Voltage Hysteresis	-	Fig. 12.2	V _{HYS}	-	0.44	-	V
Input Current	V _I = V _{DDI} ^(Note1) or 0 V	-	I _I	-	-	±1	μA
SWITCHING SPECIFICATIONS							
Data Rate	-	-	t _{bps}	DC	-	25	Mbps
Pulse Width	-	-	PW	40	-	-	ns
Propagation Delay	50 kHz, Duty = 50 % , t _r = t _f = 2 ns, C _L = 15 pF	Fig. 12.3	t _{PHL} , t _{PLH}	-	33	46	ns
DC~10Mbps							
Pulse Width Distortion	t _{PHL} – t _{PLH}	Fig. 12.3	PWD	-	0.7	8.0	ns
Propagation Delay Skew ^(Note2) (Between any two units)	-	-	t _{PSK}	-	-	16	ns
Channel Matching	Same Direction	Fig. 12.3	t _{skCD}	-	-	5.0	ns
	Opposing Direction	Fig. 12.3	t _{skOD}	-	-	7.0	
DC~25Mbps							
Pulse Width Distortion	t _{PHL} – t _{PLH}	Fig. 12.3	PWD	-	0.7	13	ns
Propagation Delay Skew ^(Note2) (Between any two units)	-	-	t _{PSK}	-	-	21	ns
Channel Matching	Same Direction	Fig. 12.3	t _{skCD}	-	-	10	ns
	Opposing Direction	Fig. 12.3	t _{skOD}	-	-	12	
Output Rise Time	10 % - 90 %	Fig. 12.3	t _r	-	2.0	-	ns
Output Fall Time	90 % - 10 %	Fig. 12.3	t _f	-	2.0	-	ns
Default output delay time from input power loss	V _{DDI} < 2.25 V → 0 V	-	t _{DO}	-	-	25	μs
Time from PU ^(Note3) to valid output data	-	-	t _{PU}	-	-	30	μs
Common mode transient immunity (Note4)	V _I = V _{DDI} or 0 V , V _{CM} = 400 V , T _a = 25°C	Fig. 12.4	CMTI	30	-	-	kV/μs

Note1: V_{DDI} = Input-side V_{DDX} , V_{DDO} = Output-side V_{DDX}

Note2: Propagation delay difference (between parts) is applied under the same operating conditions (power supply voltage, input current, temperature conditions, etc.).

Note3: PU = Powered up ($V_{DD} \geq 2.25\text{ V}$), After V_{DD} is set powered up, normal operation become valid 30 μs later.

Note4: This parameter is warranted by design.

9.2. Electrical Characteristics – 3.3 V Supply

All typical specifications are at $T_a = 25\text{ }^{\circ}\text{C}$, $V_{DD1} = V_{DD2} = 3.3\text{ V}$. Minimum/maximum specifications apply over the entire recommended operating range of $3.0\text{ V} \leq V_{DD1} \leq 3.6\text{ V}$, $3.0\text{ V} \leq V_{DD2} \leq 3.6\text{ V}$, and $-40\text{ }^{\circ}\text{C} \leq T_a \leq 125\text{ }^{\circ}\text{C}$, unless otherwise noted.

PARAMETER	TEST CONDITIONS	Fig.	SYMBOL	MIN	TYP.	MAX	UNIT
DC SPECIFICATIONS							
Output Voltage Logic High	V _{IX} = H , I _{OH} = -20 μA	Fig.12.1	V _{OH}	V _{DDO} ^(Note1) -0.1	V _{DDO} ^(Note1)	-	V
	V _{IX} = H , I _{OH} = -4 mA			V _{DDO} ^(Note1) -0.4	V _{DDO} ^(Note1) -0.2	-	
Output Voltage Logic Low	V _{IX} = L , I _{OL} = 20 μA	Fig.12.1	V _{OL}	-	0.0	0.1	V
	V _{IX} = L , I _{OL} = 4 mA			-	0.2	0.4	
Output impedance	-	Fig.12.1	Z _O	-	50	-	Ω
High-level input voltage	-	Fig.12.2	V _{IH}	0.7*V _{DDI} ^(Note1)	-	-	V
Low-level input voltage	-	Fig.12.2	V _{IL}	-	-	0.3*V _{DDI} ^(Note1)	V
Input Voltage Hysteresis	-	Fig.12.2	V _{HYS}	-	0.25	-	V
Input Current	V _I = V _{DDI} ^(Note1) or 0 V	-	I _I	-	-	±1	μA
SWITCHING SPECIFICATIONS							
Data Rate	-	-	t _{bps}	DC	-	25	Mbps
Pulse Width	-	-	PW	40	-	-	ns
Propagation Delay	50 kHz, Duty = 50 % , t _r = t _f = 2 ns, C _L = 15 pF	Fig.12.3	t _{PHL} , t _{PLH}	-	38	52	ns
DC~10Mbps							
Pulse Width Distortion	t _{PHL} – t _{PLH}	Fig.12.3	PWD	-	0.7	8.0	ns
Propagation Delay Skew ^(Note2) (Between any two units)	-	-	t _{PSK}	-	-	19	ns
Channel Matching	Same Direction	Fig.12.3	t _{skCD}	-	-	5.0	ns
	Opposing Direction	Fig.12.3	t _{skOD}	-	-	9.0	
DC~25Mbps							
Pulse Width Distortion	t _{PHL} – t _{PLH}	Fig.12.3	PWD	-	0.7	13	ns
Propagation Delay Skew ^(Note2) (Between any two units)	-	-	t _{PSK}	-	-	24	ns
Channel Matching	Same Direction	Fig.12.3	t _{skCD}	-	-	10	ns
	Opposing Direction	Fig.12.3	t _{skOD}	-	-	14	
Output Rise Time	10 % - 90 %	Fig.12.3	t _r	-	2.0	-	ns
Output Fall Time	90 % - 10 %	Fig.12.3	t _f	-	2.0	-	ns
Default output delay time from input power loss	V _{DDI} < 2.25 V → 0 V	-	t _{DO}	-	-	30	μs
Time from PU ^(Note3) to valid output data	-	-	t _{PU}	-	-	30	μs
Common mode transient immunity (Note4)	V _I = V _{DDI} or 0 V , V _{CM} = 400 V, T _a = 25°C	Fig. 12.4	CMTI	30	-	-	kV/μs

Note1: V_{DDI} = Input-side V_{DDX} , V_{DDO} = Output-side V_{DDX}

Note2: Propagation delay difference (between parts) is applied under the same operating conditions (power supply voltage, input current, temperature conditions, etc.).

Note3: PU = Powered up ($V_{DD} \geq 2.25\text{ V}$) , After V_{DD} is set powered up, normal operation become valid 30 μs later.

Note4: This parameter is warranted by design.

9.3. Electrical Characteristics – 2.5 V Supply

All typical specifications are at $T_a = 25^\circ\text{C}$, $V_{DD1} = V_{DD2} = 2.5\text{ V}$. Minimum/maximum specifications apply over the entire recommended operating range of $2.25\text{ V} \leq V_{DD1} \leq 2.75\text{ V}$, $2.25\text{ V} \leq V_{DD2} \leq 2.75\text{ V}$, and $-40^\circ\text{C} \leq T_a \leq 125^\circ\text{C}$, unless otherwise noted.

PARAMETER	TEST CONDITIONS	Fig.	SYMBOL	MIN	TYP.	MAX	UNIT
DC SPECIFICATIONS							
Output Voltage Logic High	V _{IX} = H , I _{OH} = -20 μA	Fig.12.1	V _{OH}	V _{DDO} ^(Note1) -0.1	V _{DDO} ^(Note1)	-	V
	V _{IX} = H , I _{OH} = -4 mA			V _{DDO} ^(Note1) -0.4	V _{DDO} ^(Note1) -0.2	-	
Output Voltage Logic Low	V _{IX} = L , I _{OL} = 20 μA	Fig.12.1	V _{OL}	-	0.0	0.1	V
	V _{IX} = L , I _{OL} = 4 mA			-	0.2	0.4	
Output impedance	-	Fig.12.1	Z _O	-	50	-	Ω
High-level input voltage	-	Fig.12.2	V _{IH}	0.7*V _{DDI} ^(Note1)	-	-	V
Low-level input voltage	-	Fig.12.2	V _{IL}	-	-	0.3*V _{DDI} ^(Note1)	V
Input Voltage Hysteresis	-	Fig.12.2	V _{HYS}	-	0.22	-	V
Input Current	V _I = V _{DDI} ^(Note1) or 0 V	-	I _I	-	-	±1	μA
SWITCHING SPECIFICATIONS							
Data Rate	-	-	t _{bps}	DC	-	25	Mbps
Pulse Width	-	-	PW	40	-	-	ns
Propagation Delay	50 kHz, Duty = 50 % , t _r =t _f = 2 ns, C _L = 15 pF	Fig.12.3	t _{PHL} , t _{PLH}	-	46	63	ns
DC~10Mbps							
Pulse Width Distortion	t _{PHL} – t _{PLH}	Fig.12.3	PWD	-	0.4	8.0	ns
Propagation Delay Skew ^(Note2) (Between any two units)	-	-	t _{PSK}	-	-	24	ns
Channel Matching	Same Direction	Fig.12.3	t _{skCD}	-	-	7.0	ns
	Opposing Direction	Fig.12.3	t _{skOD}	-	-	11	
DC~25Mbps							
Pulse Width Distortion	t _{PHL} – t _{PLH}	Fig.12.3	PWD	-	0.4	13	ns
Propagation Delay Skew ^(Note2) (Between any two units)	-	-	t _{PSK}	-	-	29	ns
Channel Matching	Same Direction	Fig.12.3	t _{skCD}	-	-	12	ns
	Opposing Direction	Fig.12.3	t _{skOD}	-	-	16	
Output Rise Time	10 % - 90 %	Fig.12.3	t _r	-	2.0	-	ns
Output Fall Time	90 % - 10 %	Fig.12.3	t _f	-	2.0	-	ns
Default output delay time from input power loss	V _{DDI} < 2.25 V → 0 V	-	t _{DO}	-	-	40	μs
Time from PU ^(Note3) to valid output data	-	-	t _{PU}	-	-	30	μs
Common mode transient immunity (Note4)	V _I = V _{DDI} or 0 V , V _{CM} = 400 V, T _a = 25°C	Fig. 12.4	CMTI	30	-	-	kV/μs

Note1: V_{DDI} = Input-side V_{DDX} , V_{DDO} = Output-side V_{DDX}

Note2: Propagation delay difference (between parts) is applied under the same operating conditions (power supply voltage, input current, temperature conditions, etc.).

Note3: PU = Powered up ($V_{DD} \geq 2.25\text{ V}$) , After V_{DD} is set powered up, normal operation become valid 30 μs later.

Note4: This parameter is warranted by design.

9.4. Supply Current Characteristics 5 V Supply

All typical specifications are at $T_a = 25\text{ }^{\circ}\text{C}$, $V_{DD1} = V_{DD2} = 5\text{ V}$. Minimum/maximum specifications apply over the entire recommended operating range of $4.5\text{ V} \leq V_{DD1} \leq 5.5\text{ V}$, $4.5\text{ V} \leq V_{DD2} \leq 5.5\text{ V}$, and $-40\text{ }^{\circ}\text{C} \leq T_a \leq 125\text{ }^{\circ}\text{C}$, unless otherwise noted.

(1) DCL320x00

PARAMETER	TEST CONDITIONS	SYMBOL	MIN	TYP.	MAX	UNIT
Supply Current	$V_I = 0\text{ or }1$	$I_{DD1(Q)}$	-	155	290	μA
		$I_{DD2(Q)}$	-	210	590	μA
1 Mbps	$f_{CLK} = 500\text{ kHz}$, duty = 50 % cycle square wave. No load	$I_{DD1(1)}$	-	225	345	μA
		$I_{DD2(1)}$	-	285	680	μA
1 Mbps	$f_{CLK} = 500\text{ kHz}$, duty = 50 % cycle square wave. $C_L = 15\text{ pF}$	$I_{DD1(1)}$	-	225	350	μA
		$I_{DD2(1)}$	-	375	780	μA
25 Mbps	$f_{CLK} = 12.5\text{ MHz}$, duty = 50 % cycle square wave. $C_L = 15\text{ pF}$	$I_{DD1(25)}$	-	4.8	6.9	mA
		$I_{DD2(25)}$	-	4.4	5.7	mA

(2) DCL321x00

PARAMETER	TEST CONDITIONS	SYMBOL	MIN	TYP.	MAX	UNIT
Supply Current	$V_I = 0\text{ or }1$	$I_{DD1(Q)}$	-	180	430	μA
		$I_{DD2(Q)}$	-	180	435	μA
1 Mbps	$f_{CLK} = 500\text{ kHz}$, duty = 50 % cycle square wave. No load	$I_{DD1(1)}$	-	260	515	μA
		$I_{DD2(1)}$	-	260	515	μA
1 Mbps	$f_{CLK} = 500\text{ kHz}$, duty = 50 % cycle square wave. $C_L = 15\text{ pF}$	$I_{DD1(1)}$	-	305	570	μA
		$I_{DD2(1)}$	-	305	570	μA
25 Mbps	$f_{CLK} = 12.5\text{ MHz}$, duty = 50 % cycle square wave. $C_L = 15\text{ pF}$	$I_{DD1(25)}$	-	4.7	6.3	mA
		$I_{DD2(25)}$	-	4.7	6.3	mA

9.5. Supply Current Characteristics 3.3 V Supply

All typical specifications are at $T_a = 25\text{ }^{\circ}\text{C}$, $V_{DD1} = V_{DD2} = 3.3\text{ V}$. Minimum/maximum specifications apply over the entire recommended operating range of $3.0\text{ V} \leq V_{DD1} \leq 3.6\text{ V}$, $3.0\text{ V} \leq V_{DD2} \leq 3.6\text{ V}$, and $-40\text{ }^{\circ}\text{C} \leq T_a \leq 125\text{ }^{\circ}\text{C}$, unless otherwise noted.

(1) DCL320x00

PARAMETER	TEST CONDITIONS	SYMBOL	MIN	TYP.	MAX	UNIT
Supply Current	$V_I = 0\text{ or }1$	$I_{DD1(Q)}$	-	110	210	μA
		$I_{DD2(Q)}$	-	155	465	μA
1 Mbps	$f_{CLK} = 500\text{ kHz}$, duty = 50 % cycle square wave. No load	$I_{DD1(1)}$	-	155	245	μA
		$I_{DD2(1)}$	-	200	525	μA
1 Mbps	$f_{CLK} = 500\text{ kHz}$, duty = 50 % cycle square wave. $C_L = 15\text{ pF}$	$I_{DD1(1)}$	-	160	240	μA
		$I_{DD2(1)}$	-	260	600	μA
25 Mbps	$f_{CLK} = 12.5\text{ MHz}$, duty = 50 % cycle square wave. $C_L = 15\text{ pF}$	$I_{DD1(25)}$	-	3.4	5.4	mA
		$I_{DD2(25)}$	-	2.8	3.9	mA

(2) DCL321x00

PARAMETER	TEST CONDITIONS	SYMBOL	MIN	TYP.	MAX	UNIT
Supply Current	$V_I = 0\text{ or }1$	$I_{DD1(Q)}$	-	135	335	μA
		$I_{DD2(Q)}$	-	135	335	μA
1 Mbps	$f_{CLK} = 500\text{ kHz}$, duty = 50 % cycle square wave. No load	$I_{DD1(1)}$	-	185	385	μA
		$I_{DD2(1)}$	-	185	385	μA
1 Mbps	$f_{CLK} = 500\text{ kHz}$, duty = 50 % cycle square wave. $C_L = 15\text{ pF}$	$I_{DD1(1)}$	-	215	420	μA
		$I_{DD2(1)}$	-	215	420	μA
25 Mbps	$f_{CLK} = 12.5\text{ MHz}$, duty = 50 % cycle square wave. $C_L = 15\text{ pF}$	$I_{DD1(25)}$	-	3.2	4.7	mA
		$I_{DD2(25)}$	-	3.2	4.7	mA

9.6. Supply Current Characteristics 2.5 V Supply

All typical specifications are at $T_a = 25\text{ }^{\circ}\text{C}$, $V_{DD1} = V_{DD2} = 2.5\text{ V}$. Minimum/maximum specifications apply over the entire recommended operating range of $2.25\text{ V} \leq V_{DD1} \leq 2.75\text{ V}$, $2.25\text{ V} \leq V_{DD2} \leq 2.75\text{ V}$, and $-40\text{ }^{\circ}\text{C} \leq T_a \leq 125\text{ }^{\circ}\text{C}$, unless otherwise noted

(1) DCL320x00

PARAMETER	TEST CONDITIONS	SYMBOL	MIN	TYP.	MAX	UNIT
Supply Current	$V_I = 0\text{ or }1$	$I_{DD1(Q)}$	-	100	190	μA
		$I_{DD2(Q)}$	-	140	435	μA
1 Mbps	$f_{CLK} = 500\text{ kHz}$, duty = 50 % cycle square wave. No load	$I_{DD1(1)}$	-	140	215	μA
		$I_{DD2(1)}$	-	175	475	μA
1 Mbps	$f_{CLK} = 500\text{ kHz}$, duty = 50 % cycle square wave. $C_L = 15\text{ pF}$	$I_{DD1(1)}$	-	140	220	μA
		$I_{DD2(1)}$	-	220	530	μA
25 Mbps	$f_{CLK} = 12.5\text{ MHz}$, duty = 50 % cycle square wave. $C_L = 15\text{ pF}$	$I_{DD1(25)}$	-	3.1	4.8	mA
		$I_{DD2(25)}$	-	2.1	3.0	mA

(2) DCL321x00

PARAMETER	TEST CONDITIONS	SYMBOL	MIN	TYP.	MAX	UNIT
Supply Current	$V_I = 0\text{ or }1$	$I_{DD1(Q)}$	-	125	310	μA
		$I_{DD2(Q)}$	-	125	310	μA
1 Mbps	$f_{CLK} = 500\text{ kHz}$, duty = 50 % cycle square wave. No load	$I_{DD1(1)}$	-	160	340	μA
		$I_{DD2(1)}$	-	160	340	μA
1 Mbps	$f_{CLK} = 500\text{ kHz}$, duty = 50 % cycle square wave. $C_L = 15\text{ pF}$	$I_{DD1(1)}$	-	180	365	μA
		$I_{DD2(1)}$	-	180	365	μA
25 Mbps	$f_{CLK} = 12.5\text{ MHz}$, duty = 50 % cycle square wave. $C_L = 15\text{ pF}$	$I_{DD1(25)}$	-	2.6	3.9	mA
		$I_{DD2(25)}$	-	2.6	3.9	mA

10. Insulation Specifications

PARAMETER	Symbol	TEST CONDITIONS	VALUE	UNIT
Minimum External Clearance	CLR	Shortest terminal-to-terminal distance through air	3.8	mm
Minimum External Creepage	CPG	Shortest terminal-to-terminal distance across the package surface	3.8	mm
Distance Through The Insulation	DTI	Minimum internal gap	8.5	μm
Comparative Tracking Index	CTI	-	400	V
Material Group	-	According to IEC 60664-1	II	-
Overvoltage Category Per IEC 60664-1	-	Related Mains Voltage $\leq 300 V_{rms}$	I-III	-
DIN EN IEC 60747-17; (VDE 0884-17)				
Maximum Repetitive Peak Isolation Voltage	V_{IORM}	AC voltage (bipolar)	566	V_{PK}
Maximum Transient Isolation Voltage	V_{IOTM}	$V_{TEST} = V_{IOTM}$, $t = 60$ s (qualification), $V_{TEST} = 1.2 \times V_{IOTM}$, $t = 1$ s (100 % production)	4243	V_{PK}
Maximum Impulse Voltage	V_{IMP}	IEC 62368-1 1.2/50 μs waveform	4000	V_{PK}
Maximum surge isolation voltage	V_{IOSM}	Test method per IEC 61000-4-5, 1.2/50 μs waveform, $V_{IOSM} \geq 1.3 \times V_{IMP}$ (qualification)	5200	V_{PK}
Apparent charge measuring voltage	$V_{pd(m)}$	Method A, After Input/Output safety test subgroup 2&3, $V_{ini,a} = V_{IOTM}$, $V_{pd(m)} = 1.2 \times V_{IORM}$ $t_{ini} = 60$ s, $t_m = 10$ s, partial discharge < 5 pC	680	V_{PK}
		Method A, After environmental tests subgroup 1, $V_{ini,a} = V_{IOTM}$, $V_{pd(m)} = 1.3 \times V_{IORM}$ $t_{ini} = 60$ s, $t_m = 10$ s, partial discharge < 5 pC	736	
		Method B1; At routine test (100 % production) and preconditioning (type test) $V_{ini,b} \geq 1.2 \times V_{IOTM}$, $V_{pd(m)} = 1.5 \times V_{IORM}$ $t_{ini,b} = 1$ s, $t_m = 1$ s partial discharge < 5 pC	849	
Barrier capacitance, input to output	C_{IO}	$f = 1$ MHz	1.2	pF
Input Capacitance	C_I	input : V_{I1}	4.4	pF
		input : V_{I2}	3.9	
Isolation Resistance	R_{IO}	$V_{IO} = 500$ V, $T_a = 25$ °C	$>10^{12}$	Ω
		$V_{IO} = 500$ V, 100 °C $\leq T_a \leq 125$ °C	$>10^{11}$	
		$V_{IO} = 500$ V at $T_s = 150$ °C	$>10^9$	
Pollution Degree	-	-	2	-
Climatic Category	-	-	40/125/21	-
UL 1577				
Maximum Withstand Isolation Voltage	V_{ISO}	$V_{TEST} = V_{ISO}$, $t = 60$ s (qualification), $V_{TEST} = 1.2 \times V_{ISO}$, $t = 1$ s (100 % production)	3000	V_{rms}

11. Safety Limiting Values

PARAMETER	Symbol	TEST CONDITIONS	Value	Unit
Safety Input, Output or Supply Current	I _S	V _{DD1} = V _{DD2} = 5.5 V, T _j = 150 °C, T _a = 25 °C	255	mA
		V _{DD1} = V _{DD2} = 3.6 V, T _j = 150 °C, T _a = 25 °C	390	mA
		V _{DD1} = V _{DD2} = 2.75 V, T _j = 150 °C, T _a = 25 °C	511	mA
Safety Input, Output or Total Power	P _S	T _j = 150°C, T _a = 25°C	1404	W
Maximum Safety Temperature	T _S	-	150	°C

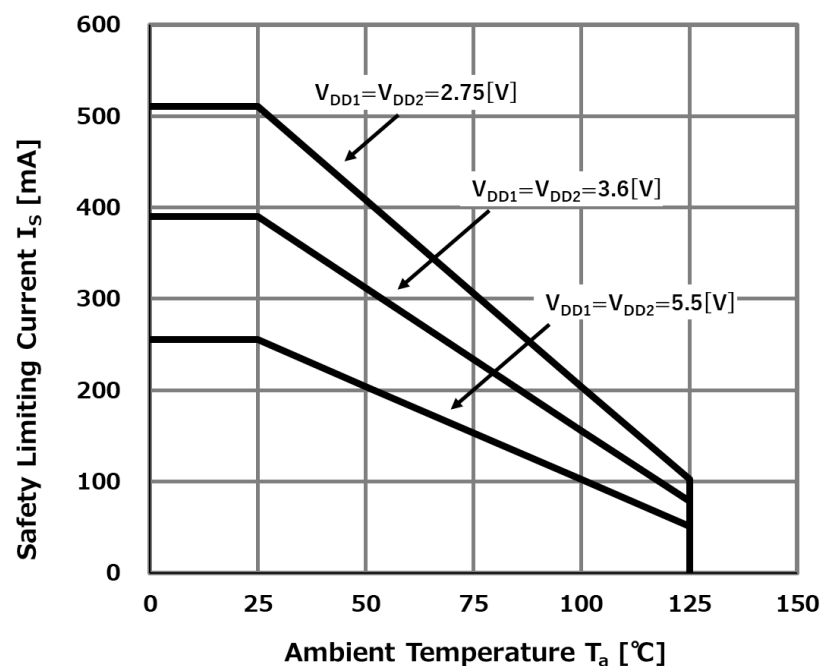


Fig. 11.1 Thermal Derating Curve for Safety Limiting Current- T_a

12. Test Circuit

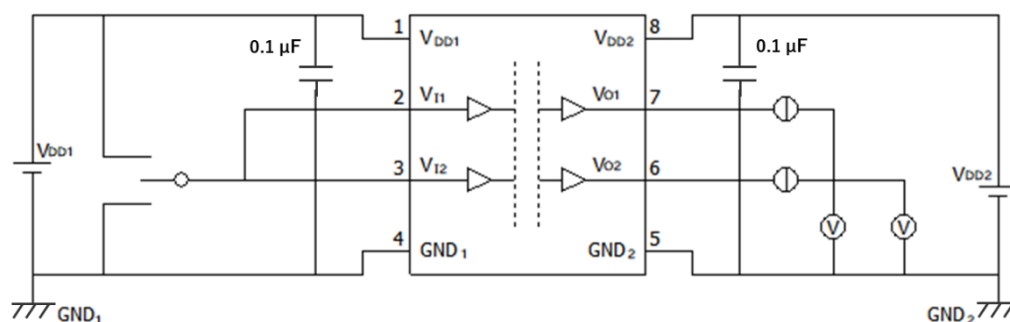


Fig. 12.1 (A) DCL320C00/DCL320D00 V_{OH}/V_{OL} Test Circuit

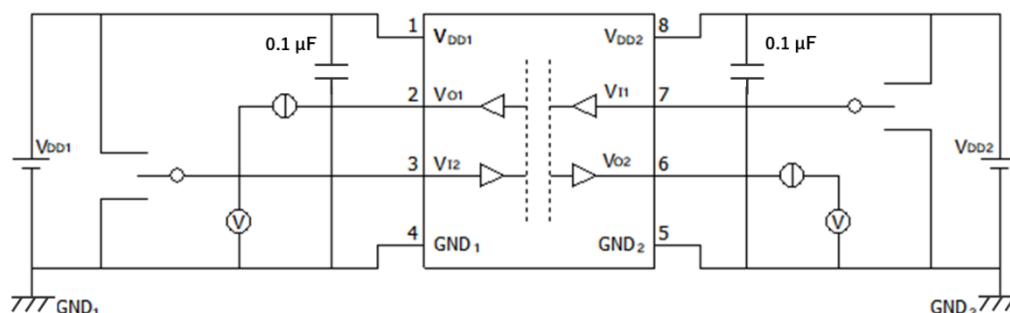


Fig. 12.1 (B) DCL321C00/DCL321D00 V_{OH}/V_{OL} Test Circuit

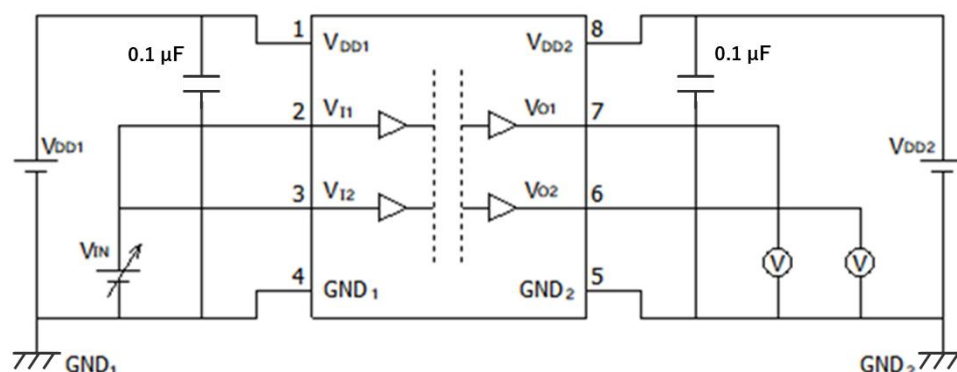


Fig. 12.2 (A) DCL320C00/DCL320D00 V_{IH}/V_{IL} Test Circuit

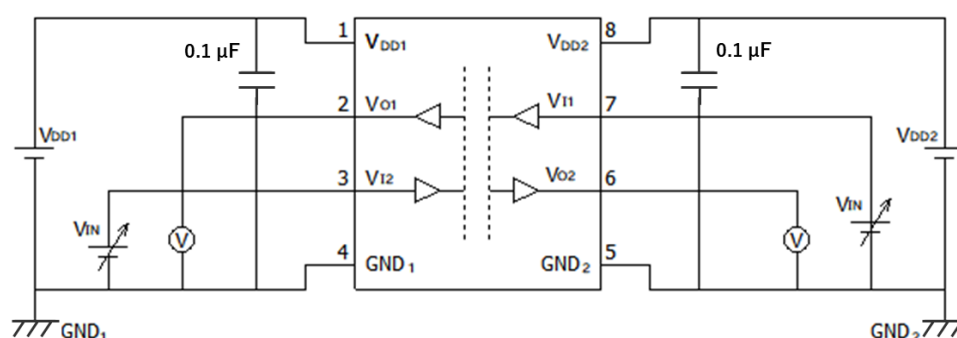


Fig. 12.2 (B) DCL321C00/DCL321D00 V_{IH}/V_{IL} Test Circuit

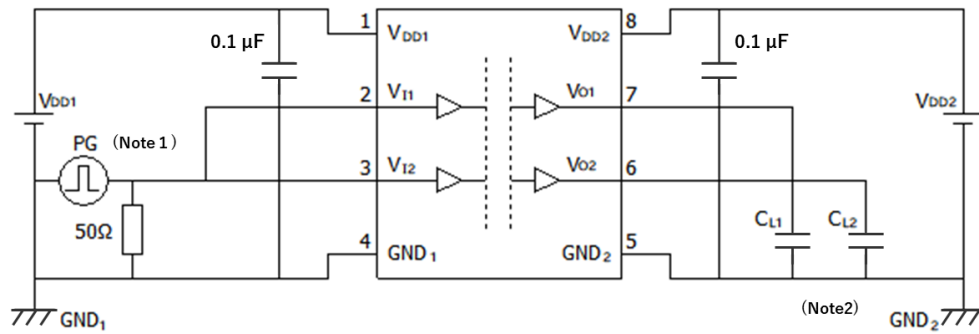


Fig.12.3 (A) DCL320C00/DCL320D00 Switching Test Circuit

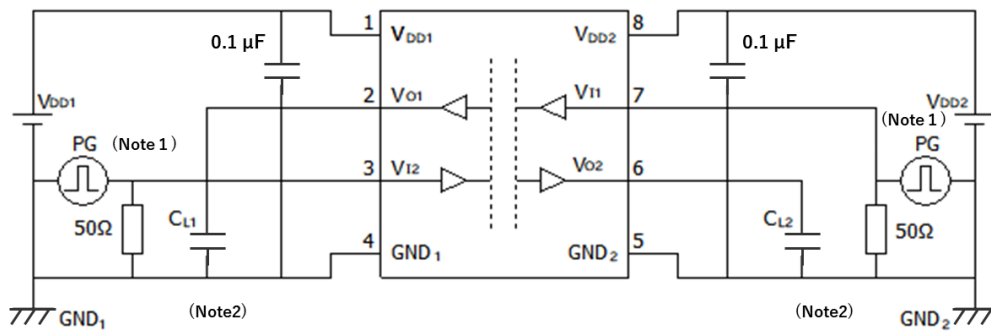


Fig.12.3 (B) DCL321C00/DCL321D00 Switching Test Circuit

Note1: The input pulse is supplied by a generator having the following characteristics: $PRR \leq 50 \text{ kHz}$, 50 % duty cycle, $t_r \leq 2 \text{ ns}$, $t_f \leq 2 \text{ ns}$, $Z_o = 50 \Omega$. At the input, 50Ω resistor is required to terminate input generator signal. It is needed not in actual application.

Note2: $C_{LX} = 15 \text{ pF}$ includes instrumentation and fixture capacitance.

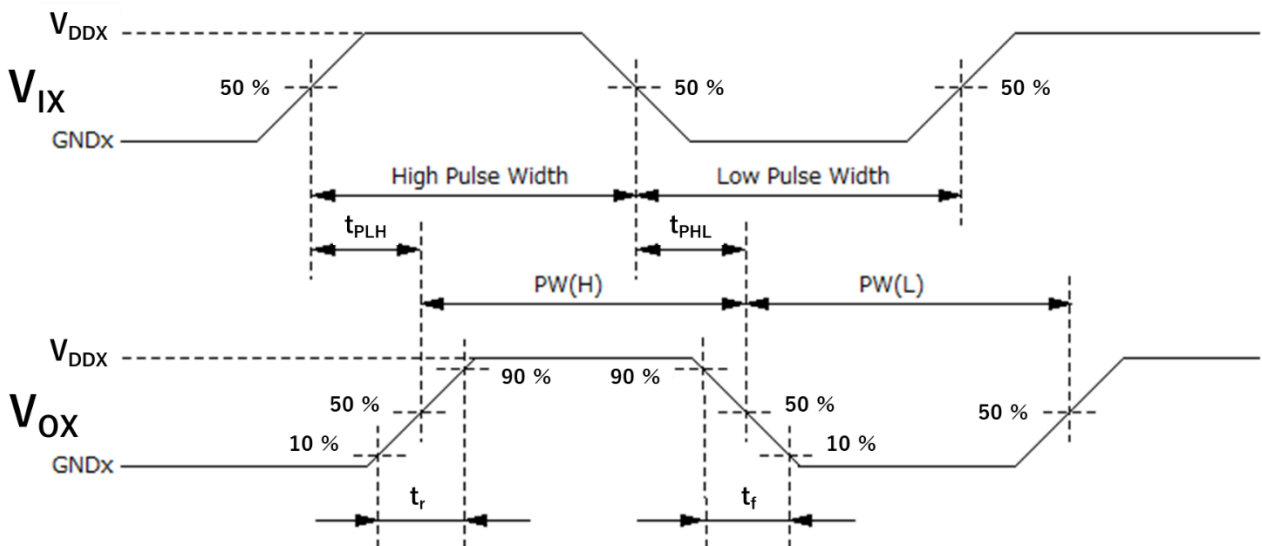


Fig.12.3 (C) Switching Test Circuit and Voltage Waveforms

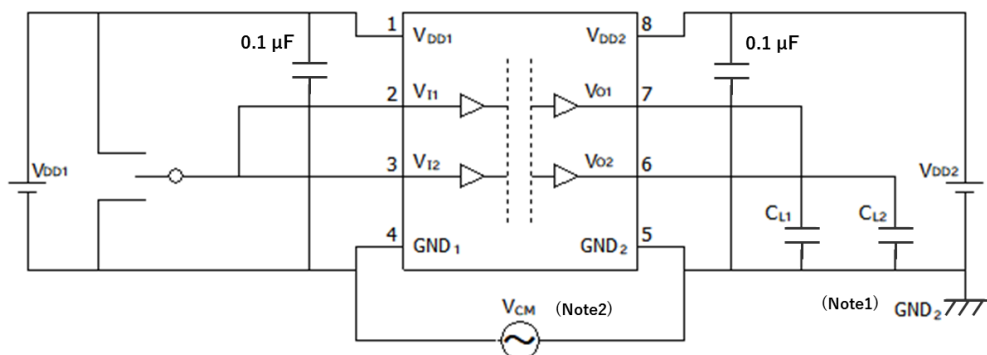


Fig.12.4 (A) DCL320C00/DCL320D00 Common-Mode Transient Immunity Test Circuit

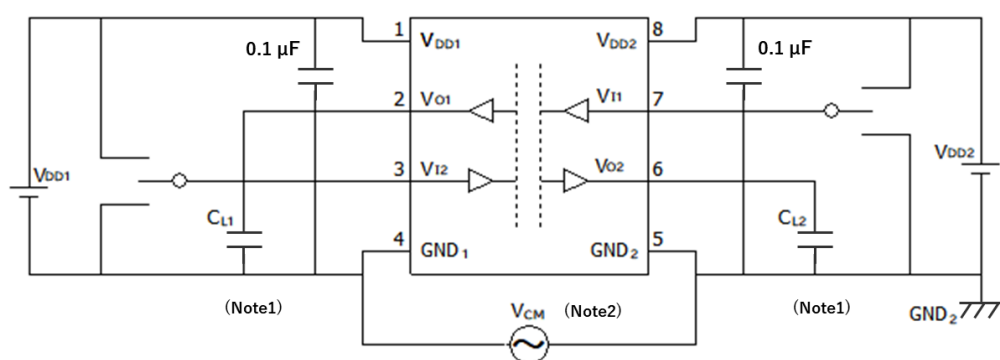


Fig.12.4 (B) DCL321C00/DCL321D00 Common-Mode Transient Immunity Test Circuit

Note1: $C_{LX} = 15 \text{ pF}$ includes instrumentation and fixture capacitance.

Note2: Apply V_{CM} with reference to the GND terminal on the output terminal side of the IC. The GND on the IC input terminal side is isolated from the output terminal side. Depending on which channel is being measured, V_{CM} may be applied with reference to GND₁ or with reference to GND₂.

13. Characteristics Curves (Note)

Note: The following characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.

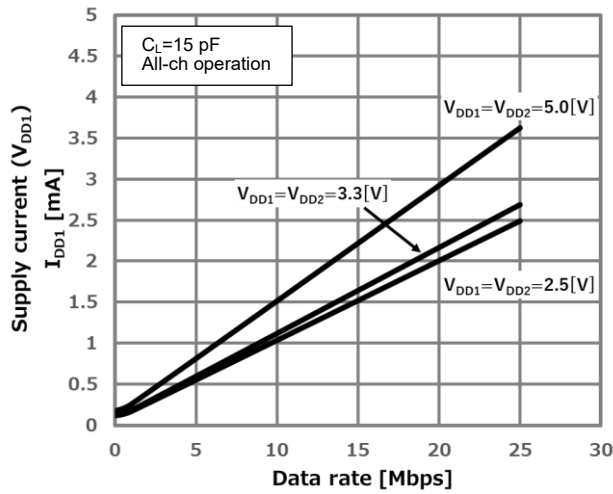


Fig.13.1. DCL321x00 I_{DD1} Supply Current - Data rate

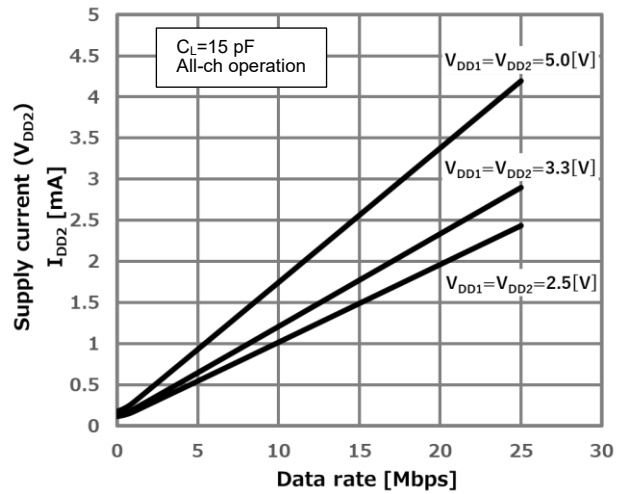


Fig.13.2. DCL321x00 I_{DD2} Supply Current - Data rate

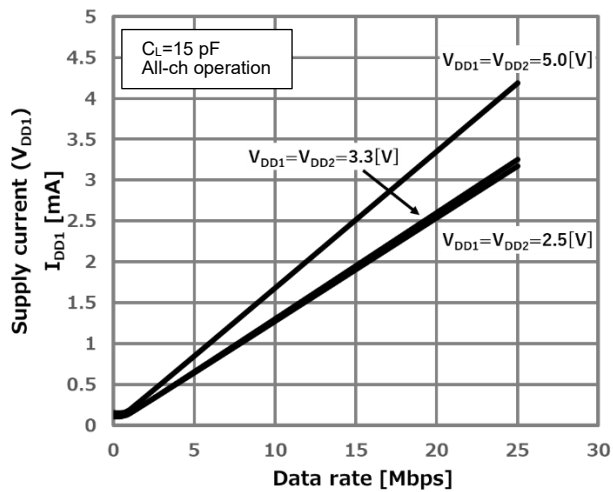


Fig.13.3. DCL320x00 I_{DD1} Supply Current - Data rate

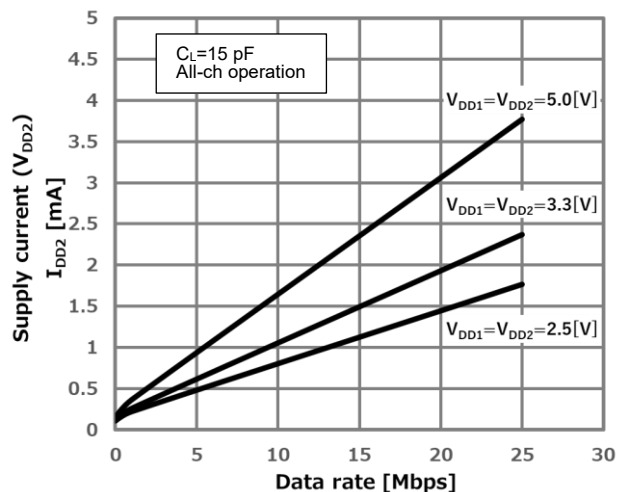


Fig.13.4. DCL320x00 I_{DD2} Supply Current - Data rate

Note: The following characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.

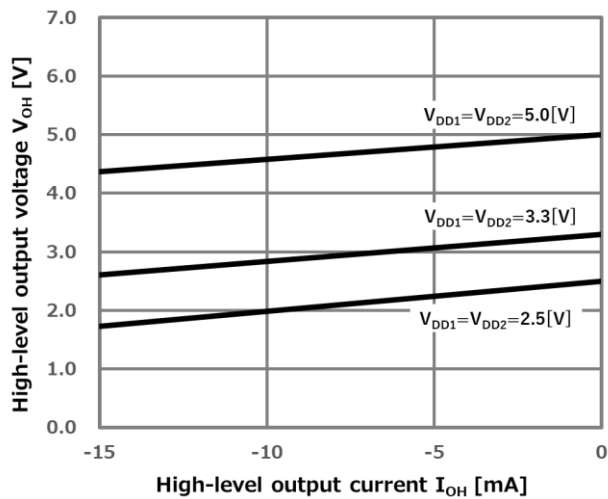


Fig.13.5. $V_{OH}-I_{OH}$

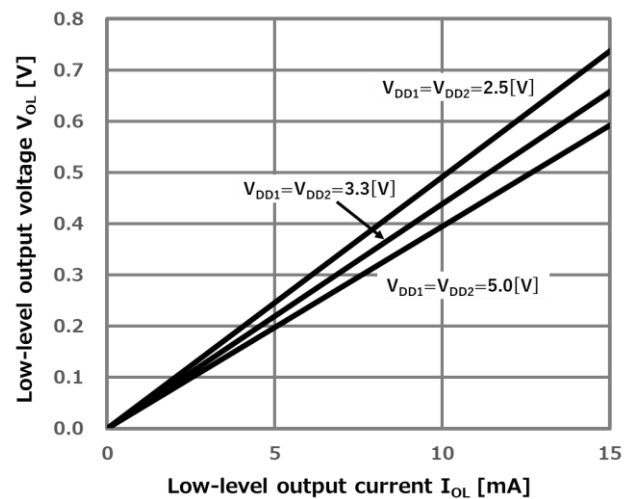


Fig.13.6. $V_{OL}-I_{OL}$

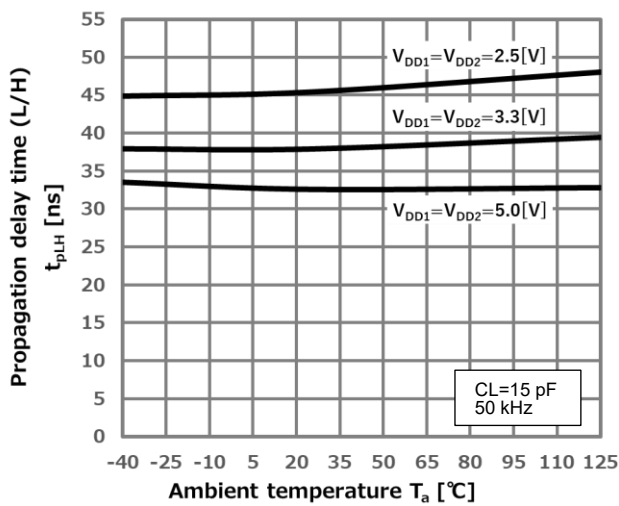


Fig.13.7. Propagation Delay Time $t_{PLH}-T_a$

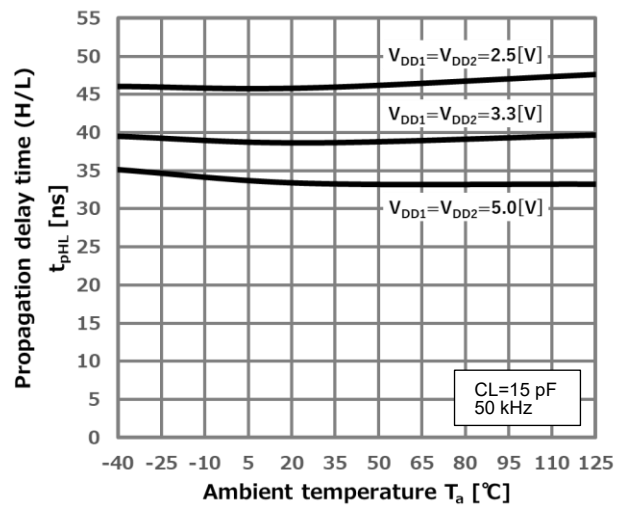
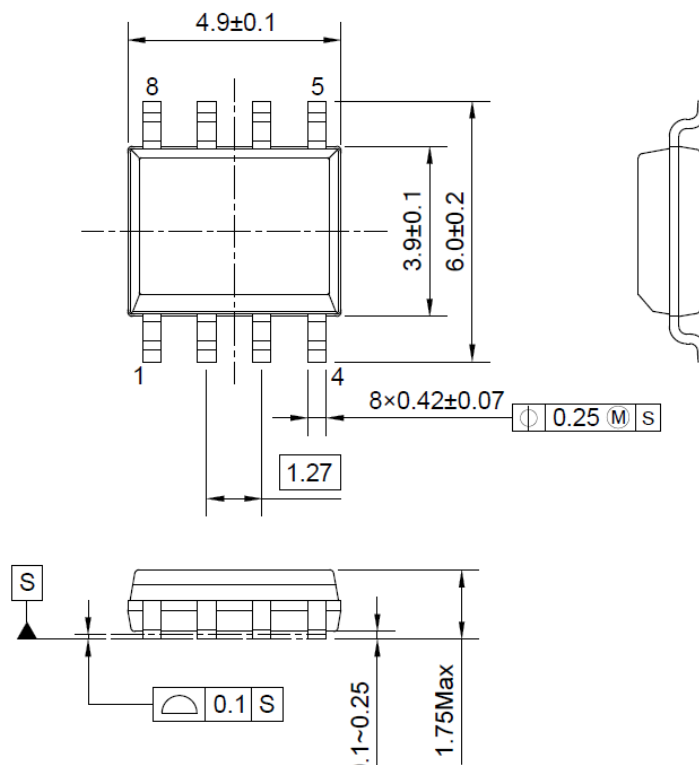
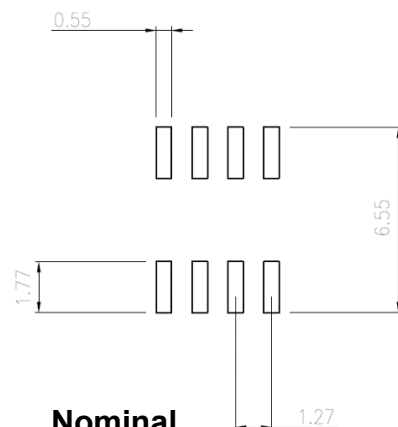
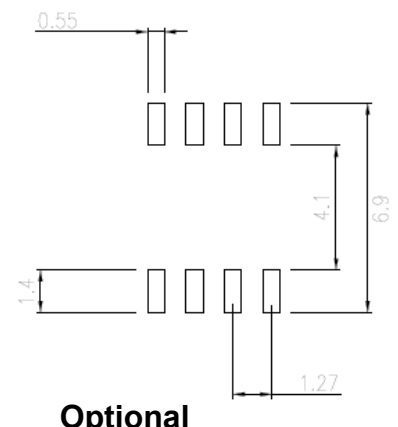


Fig.13.8. Propagation Delay Time $t_{PLH}-T_a$

14. Package Information

Package Name	SOIC8-N (P-SOP8-0405-1.27-002)
Implementation category	Surface Mount
Pin Number	8
Weight (g)	0.072 (Typ.)
Package Dimension (mm) Width × Length × Height	4.9 × 6.0 × 1.75(Max)
Package Dimension (mm)	
Land Pattern Example (mm) [for reference only]	 Nominal  Optional Large interval between primary-secondary side Notes: Land Pattern Dimensions • All linear dimensions are given in millimeters unless otherwise specified. • This drawing is based on JEITA ET-7501 Level3 and should be treated as a reference only. • TOSHIBA is not responsible for any incorrect or incomplete drawings and information. • You are solely responsible for all aspects of your own land pattern, including but not limited to soldering processes. • The drawing shown may not accurately represent the actual shape or dimensions. • Before creating and producing designs and using, customers must also refer to and comply with the latest versions of all relevant TOSHIBA information and the instructions for the application that Product will be used with or for.

15.Ordering guide

Model	V _{DD1} end Number of inputs	V _{DD2} end Number of inputs	Default Output	Data rate [Mbps]	Control signal	Temperature range [°C]	Package
DCL320C00	2	0	L	25	-	-40 ~ 125	SOIC8-N
DCL320D00	2	0	H	25	-	-40 ~ 125	SOIC8-N
DCL321C00	1	1	L	25	-	-40 ~ 125	SOIC8-N
DCL321D00	1	1	H	25	-	-40 ~ 125	SOIC8-N

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